

# TRANSISTOR MODULE

# SQD300AA120

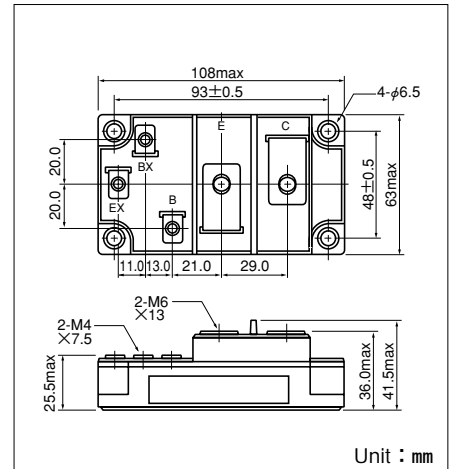
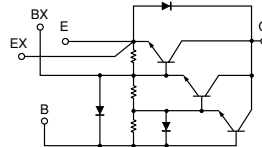
UL;E76102 (M)

SQD300AA120 is a Darlington power transistor module with a high speed, high power Darlington transistor. The transistor has a reverse paralled fast recovery diode. The mounting base of the module is electrically isolated from semiconductor elements for simple heatsink construction.

- $I_C=300A$ ,  $V_{CEX}=1200V$
- Low saturation voltage for higher efficiency.
- High DC current gain  $h_{FE}$
- Isolated mounting base

### (Applications)

Motor Control (VVVF), AC/DC Servo, UPS,  
Switching Power Supply, Ultrasonic Application



Unit : mm

### Maximum Ratings

( $T_j=25^\circ C$  unless otherwise specified)

| Symbol    | Item                      | Conditions       | Ratings                           |          | Unit            |
|-----------|---------------------------|------------------|-----------------------------------|----------|-----------------|
|           |                           |                  | SQD300AA120                       |          |                 |
| $V_{CB0}$ | Collector-Base Voltage    |                  | 1200                              |          | V               |
| $V_{CEX}$ | Collector-Emitter Voltage | $V_{BE}=-2V$     | 1200                              |          | V               |
| $V_{EB0}$ | Emitter-Base Voltage      |                  | 10                                |          | V               |
| $I_C$     | Collector Current         |                  | 300                               |          | A               |
| $-I_C$    | Reverse Collector Current |                  | 300                               |          | A               |
| $I_B$     | Base Current              |                  | 16                                |          | A               |
| $P_T$     | Total power dissipation   | $T_c=25^\circ C$ | 2000                              |          | W               |
| $T_j$     | Junction Temperature      |                  | -40 to +150                       |          | $^\circ C$      |
| $T_{stg}$ | Storage Temperature       |                  | -40 to +125                       |          | $^\circ C$      |
| $V_{iso}$ | Isolation Voltage         | A.C.1minute      | 2500                              |          | V               |
|           | Mounting Torque           | (M6)             | Recommended Value 2.5-3.9 (25-40) | 4.7 (48) | N·m<br>(kgf·cm) |
|           |                           | Terminal (M6)    | Recommended Value 2.5-3.9 (25-40) | 4.7 (48) |                 |
|           |                           | Terminal (M4)    | Recommended Value 1.0-1.4 (10-14) | 1.5 (15) |                 |
|           | Mass                      | Typical Value    | 470                               |          | g               |

### Electrical Characteristics

| Symbol         | Item                                 | Conditions                | Ratings                                                  |       | Unit         |
|----------------|--------------------------------------|---------------------------|----------------------------------------------------------|-------|--------------|
|                |                                      |                           | Min.                                                     | Max.  |              |
| $I_{CB0}$      | Collector Cut-off Current            | $V_{CB}=1200V$            |                                                          | 4.0   | mA           |
| $I_{EB0}$      | Emitter Cut-off Current              | $V_{EB}=10V$              |                                                          | 1200  | mA           |
| $V_{CEX(SUS)}$ | Collector Emitter Sustaining Voltage | $I_C=60A$ , $I_{B2}=-12A$ | 1200                                                     |       | V            |
| $h_{FE}$       | DC Current Gain                      | $I_C=300A$ , $V_{CE}=5V$  | 75                                                       |       |              |
| $V_{CE(sat)}$  | Collector-Emitter Saturation Voltage | $I_C=300A$ , $I_B=6A$     |                                                          | 3.0   | V            |
| $V_{BE(sat)}$  | Base-Emitter Saturation Voltage      | $I_C=300A$ , $I_B=6A$     |                                                          | 3.5   | V            |
| $t_{on}$       | Switching Time                       | On Time                   |                                                          | 3.0   | $\mu s$      |
| $t_s$          |                                      | Storage Time              | $V_{CC}=600V$ , $I_C=300A$<br>$I_{B1}=6A$ , $I_{B2}=-6A$ | 15.0  |              |
| $t_f$          |                                      | Fall Time                 |                                                          | 3.0   |              |
| $V_{ECO}$      | Collector-Emitter Reverse Voltage    | $I_C=-300A$               |                                                          | 1.8   | V            |
| $R_{th(j-c)}$  | Thermal Impedance (junction to case) | Transistor part           |                                                          | 0.063 | $^\circ C/W$ |
|                |                                      | Dioe part                 |                                                          | 0.3   |              |